



Docket No.: 57810-033

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of :
Nobuhiko HAYASHI, et al. :
Serial No.: 10/084,050 : Group Art Unit: 2812
Filed: February 28, 2002 : Examiner: D. Le
For: NITRIDE-BASED SEMICONDUCTOR ELEMENT AND METHOD OF FORMING
NITRIDE-BASED SEMICONDUCTOR

PETITION FOR EXTENSION OF TIME

Commissioner for Patents
Washington, DC 20231

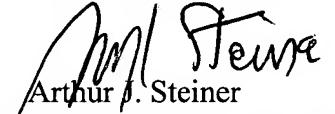
Sir:

It is respectfully requested that the time for response to the Office Action dated October 2, 2002, now due to expire November 2, 2002, be extended for one month(s) and set to expire on December 2, 2002.

Please charge the extension fee of \$110.00 to Deposit Account No. 500417. Please charge any additional fees or credit any overpayment to Deposit Account No. 500417.

Respectfully submitted,

MCDERMOTT, WILL & EMERY


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